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	Filing Date		2006-06-07
	First Named Inventor	Tetsuo Fujii	
	Art Unit	2811	
	Examiner Name		
	Attorney Docket Number	30794.108-US-WO	

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1	Japanese Office Action dated 08/31/2010, Patent Application No. 2005-512858.	<input type="checkbox"/>
2	NG, H. et al., "GaN nanotip pyramids formed by anisotropic etching," Journal of Applied Physics, vol. 94, no. 1, 1 July 2003, pp. 650-653.	<input type="checkbox"/>

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